INA6017AC1

FOR LOW FREQUENCY AMPLIFY APPLICATION
SILICON PNP EPITAXIAL TYPE

DESCRIPTION

INA6017AC1 is a silicon PNP transistor.

It is designed with high voltage.

FEATURE

・Small package for easy mounting.

・High voltage V_{CEO} = −150V

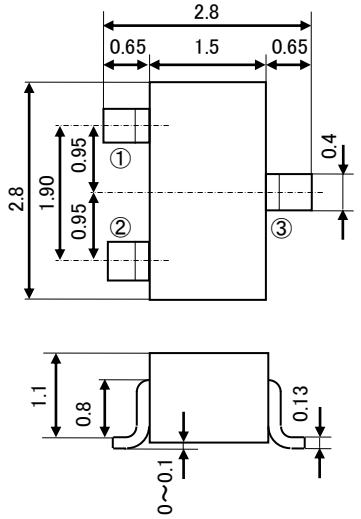
・Low voltage VCE(sat) = −0.2V(MAX)

APPLICATION

High voltage switching

OUTLINE DRAWING

UNIT : mm



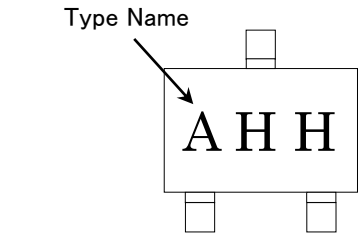
Terminal Connector
①: Base
②: Emitter
③: Collector

JEITA:SC-59
JEDEC: Similar to TO-236

MAXIMUM RATING (Ta=25℃)

SYMBOL	PARAMETER	RATING	UNIT
V_{CBO}	Collector to Base voltage	−160	V
V_{EBO}	Emitter to Base voltage	−5	V
V_{CEO}	Collector to Emitter voltage	−150	V
I_{CM}	Peak collector current	−200	mA
I_C	Collector current	−100	mA
P_C	Collector dissipation(Ta=25℃)	200	mW
T_j	Junction temperature	+150	℃
T_{stg}	Storage temperature	−55～+150	℃

MARKING

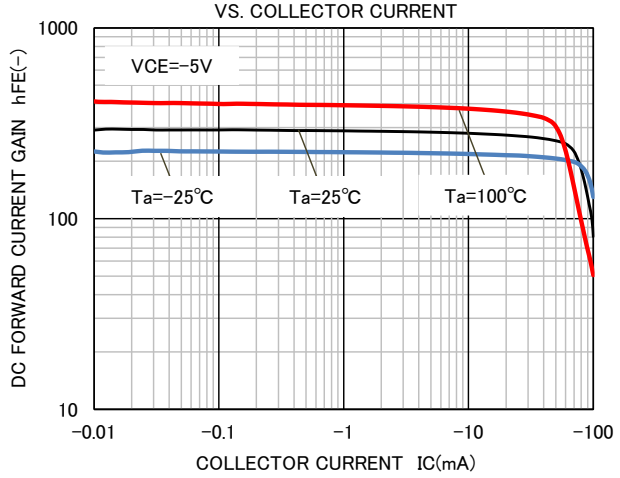


ELECTRICAL CHARACTERISTICS (Ta=25℃)

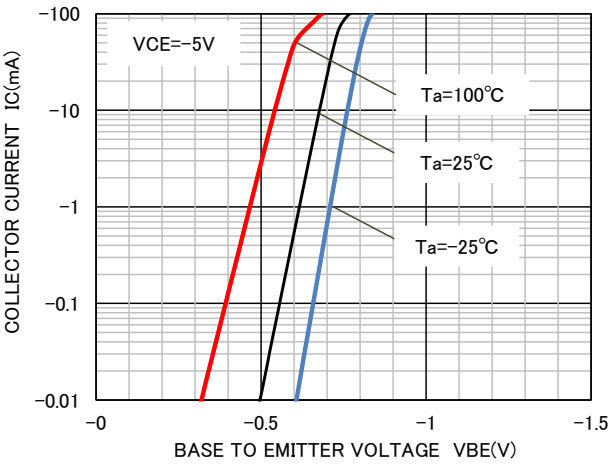
SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
$V_{(BR)CBO}$	C to B breakdown voltage	I_C=−100μA, I_E=0mA	−160	−	−	V
$V_{(BR)EBO}$	E to B breakdown voltage	I_E=−10μA, I_C=0mA	−5	−	−	V
$V_{(BR)CEO}$	C to E breakdown voltage	I_C=−1mA, R_{BE}=∞	−150	−	−	V
I_{CBO}	Collector cut off current	V_{CB}=−120V, I_E=0mA	−	−	−100	nA
I_{EBO}	Emitter cut off current	V_{EB}=−3V, I_C=0mA	−	−	−100	nA
hFE1	DC forward current gain1	VCE=−5V, I_C=−1mA	150	−	−	−
hFE2	DC forward current gain2	VCE=−5V, I_C=−10mA	200	−	500	−
hFE3	DC forward current gain3	VCE=−5V, I_C=−50mA	45	−	−	−
VCE(sat)	C to E saturation voltage	I_C=−10mA, I_B=−1mA	−	−	−0.2	V
VBE(sat)	B to E saturation voltage	I_C=−10mA, I_B=−1mA	−	−	−1.0	V
fT	Gain bandwidth product	VCE=−10V, I_E=10mA	−	130	−	MHz
Cob	Collector output capacitance	VCB=−10V, I_E=0mA, f=1MHz	−	3	−	pF

TYPICAL CHARACTERISTICS

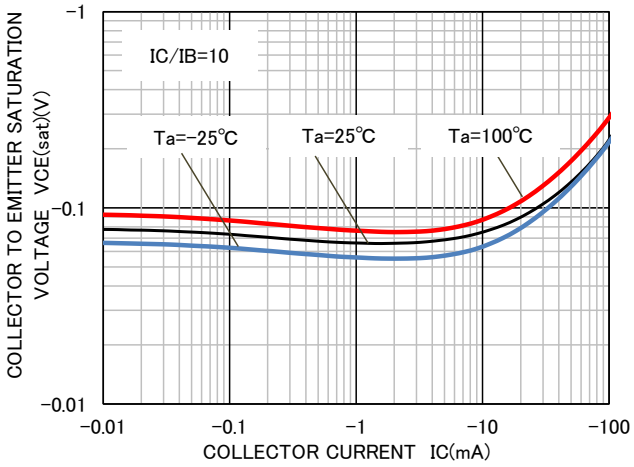
DC FORWARD CURRENT GAIN VS. COLLECTOR CURRENT



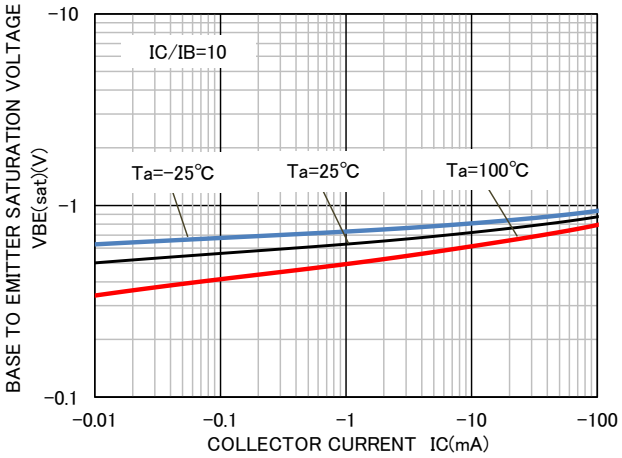
COMMON EMITTER TRANSFER



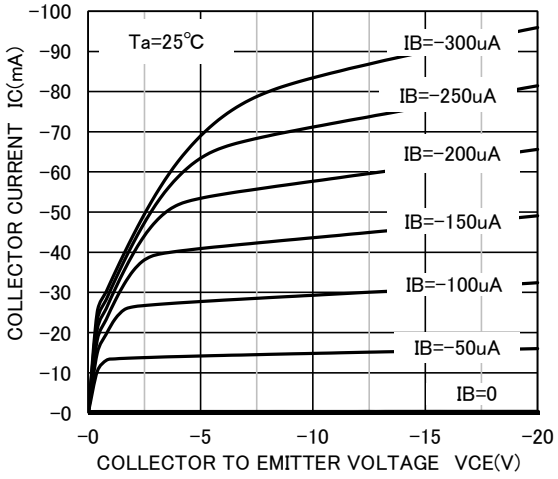
COLLECTOR TO EMITTER SATURATION VOLTAGE VS. COLLECTOR CURRENT



BASE TO EMITTER SATURATION VOLTAGE VS. COLLECTOR CURRENT



COMMON EMITTER OUTPUT



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